

Si-PIN-Fotodiode mit Tageslichtsperrfilter; in SMT und als Reverse Gullwing Silicon PIN Photodiode with Daylight Filter; in SMT and as Reverse Gullwing

BPW 34 FA, BPW 34 FAS, BPW 34 FAS (R18R)



BPW 34 FA



BPW 34 FAS



BPW 34 FAS (R18R)

Wesentliche Merkmale

- Speziell geeignet für den Wellenlängenbereich von 830 nm bis 880 nm
- Kurze Schaltzeit (typ. 20 ns)
- DIL-Plastikbauform mit hoher Packungsdichte
- BPW 34 FAS/(R18R): geeignet für Vapor-Phase Löten und IR-Reflow Löten

Anwendungen

- IR-Fernsteuerung von Fernseh- und Rundfunkgeräten, Videorecordern, Gerätefernsteuerung
- Lichtschranken für Gleich- und Wechsellichtbetrieb

Features

- Especially suitable for the wavelength range of 830 nm to 880 nm
- Short switching time (typ. 20 ns)
- DIL plastic package with high packing density
- BPW 34 FAS/(R18R): Suitable for vapor-phase and IR-reflow soldering

Applications

- IR-remote control of hi-fi and TV sets, video tape recorders, remote controls of various equipment
- Photointerrupters

Typ Type	Bestellnummer Ordering Code
BPW 34 FA	Q62702-P1129
BPW 34 FAS	Q62702-P463
BPW 34 FAS (R18R)	Q62702-P1829

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{op}; T_{stg}$	- 40 ... + 100	°C
Sperrspannung Reverse voltage	V_R $V_R (t < 2 \text{ min})$	16 32	V V
Verlustleistung, $T_A = 25 \text{ °C}$ Total power dissipation	P_{tot}	150	mW

Kennwerte ($T_A = 25 \text{ °C}$, $\lambda = 870 \text{ nm}$)
Characteristics

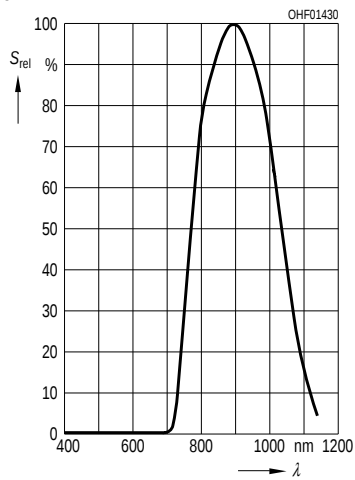
Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Fotostrom Photocurrent $V_R = 5 \text{ V}$, $E_e = 1 \text{ mW/cm}^2$	I_p	50 (≥ 40)	μA
Wellenlänge der max. Fotoempfindlichkeit Wavelength of max. sensitivity	$\lambda_{S \text{ max}}$	880	nm
Spektraler Bereich der Fotoempfindlichkeit $S = 10\%$ von S_{max} Spectral range of sensitivity $S = 10\%$ of S_{max}	λ	730 ... 1100	nm
Bestrahlungsempfindliche Fläche Radiant sensitive area	A	7.00	mm^2
Abmessung der bestrahlungsempfindlichen Fläche Dimensions of radiant sensitive area	$L \times B$ $L \times W$	2.65×2.65	$\text{mm} \times \text{mm}$
Halbwinkel Half angle	φ	± 60	Grad deg.
Dunkelstrom, $V_R = 10 \text{ V}$ Dark current	I_R	2 (≤ 30)	nA
Spektrale Fotoempfindlichkeit Spectral sensitivity	S_λ	0.65	A/W
Quantenausbeute Quantum yield	η	0.93	<u>Electrons</u> Photon
Leerlaufspannung, $E_e = 0.5 \text{ mW/cm}^2$ Open-circuit voltage	V_O	320 (≥ 250)	mV

Kennwerte ($T_A = 25\text{ °C}$, $\lambda = 870\text{ nm}$)

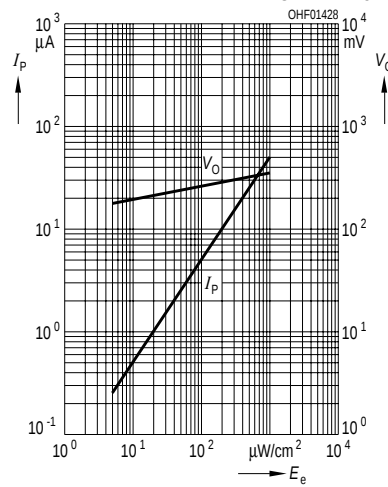
Characteristics (cont'd)

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Kurzschlußstrom, $E_e = 0.5\text{ mW/cm}^2$ Short-circuit current	I_{SC}	23	μA
Anstiegs- und Abfallzeit des Fotostromes Rise and fall time of the photocurrent $R_L = 50\text{ }\Omega$; $V_R = 5\text{ V}$; $\lambda = 850\text{ nm}$; $I_p = 800\text{ }\mu\text{A}$	t_r, t_f	20	ns
Durchlaßspannung, $I_F = 100\text{ mA}$, $E = 0$ Forward voltage	V_F	1.3	V
Kapazität, $V_R = 0\text{ V}$, $f = 1\text{ MHz}$, $E = 0$ Capacitance	C_0	72	pF
Temperaturkoeffizient von V_O Temperature coefficient of V_O	TC_V	- 2.6	mV/K
Temperaturkoeffizient von I_{SC} Temperature coefficient of I_{SC}	TC_I	0.03	%/K
Rauschäquivalente Strahlungsleistung Noise equivalent power $V_R = 10\text{ V}$	NEP	3.9×10^{-14}	$\frac{\text{W}}{\sqrt{\text{Hz}}}$
Nachweisgrenze, $V_R = 10\text{ V}$, Detection limit	D^*	6.8×10^{12}	$\frac{\text{cm} \times \sqrt{\text{Hz}}}{\text{W}}$

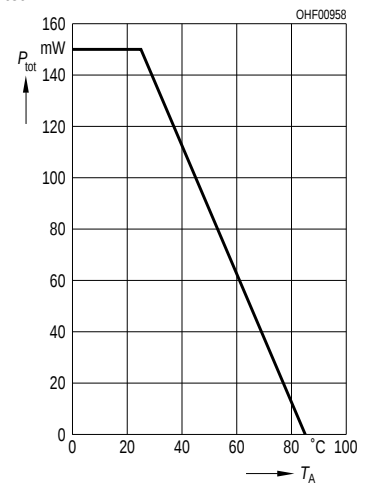
Relative Spectral Sensitivity
 $S_{\text{rel}} = f(\lambda)$



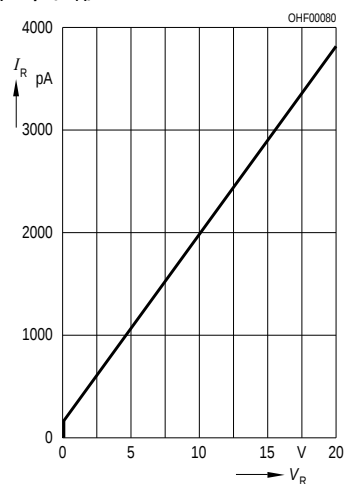
Photocurrent $I_P = f(E_e)$, $V_R = 5 \text{ V}$
Open-Circuit Voltage $V_O = f(E_e)$



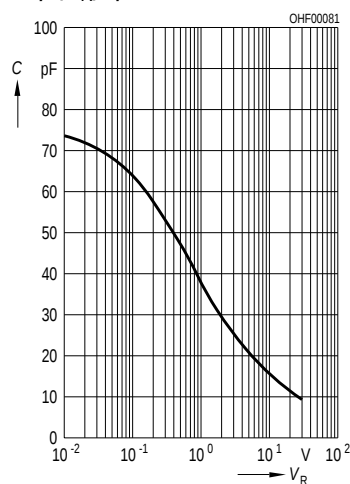
Total Power Dissipation
 $P_{\text{tot}} = f(T_A)$



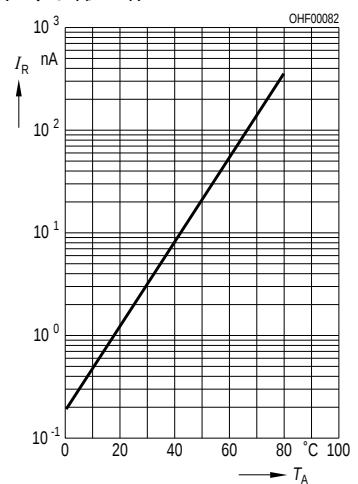
Dark Current
 $I_R = f(V_R, E = 0)$



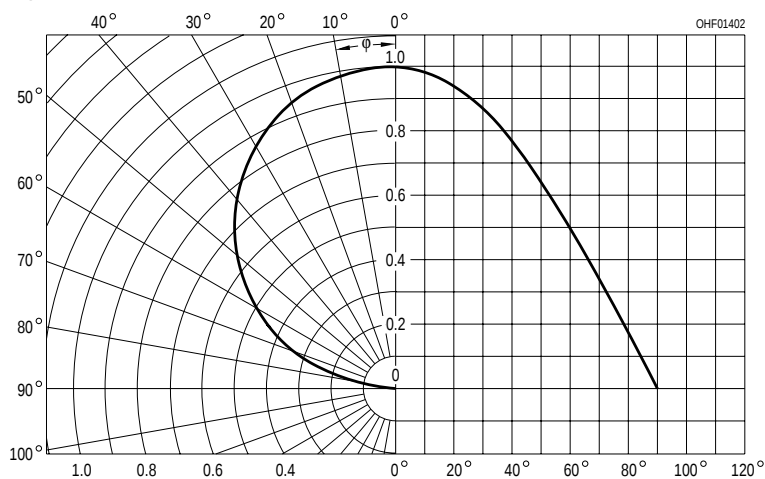
Capacitance
 $C = f(V_R, f = 1 \text{ MHz}, E = 0)$



Dark Current
 $I_R = f(T_A, V_R = 10 \text{ V}, E = 0)$

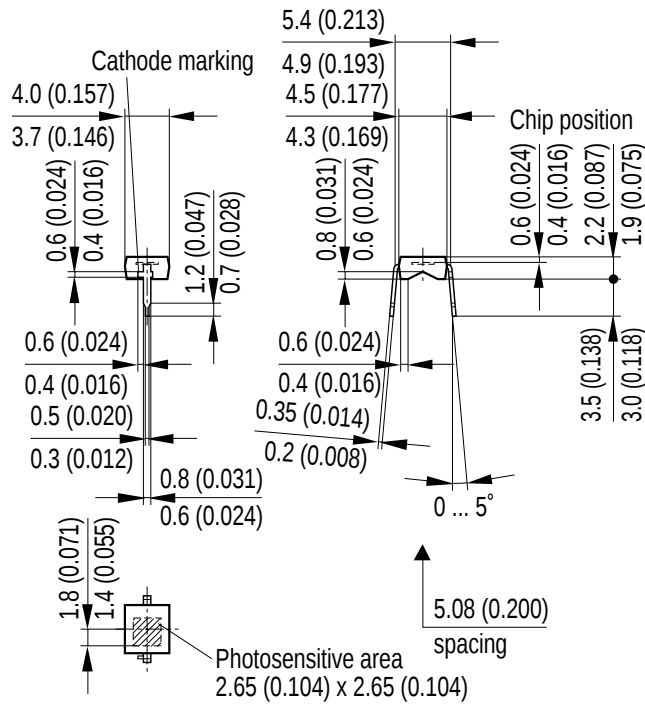


Directional Characteristics
 $S_{\text{rel}} = f(\phi)$



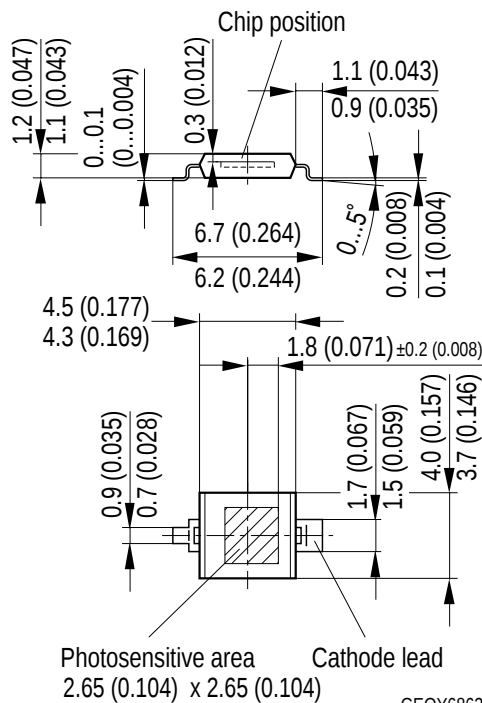
Maßzeichnung
Package Outlines

BPW 34 FA



GEOY6643

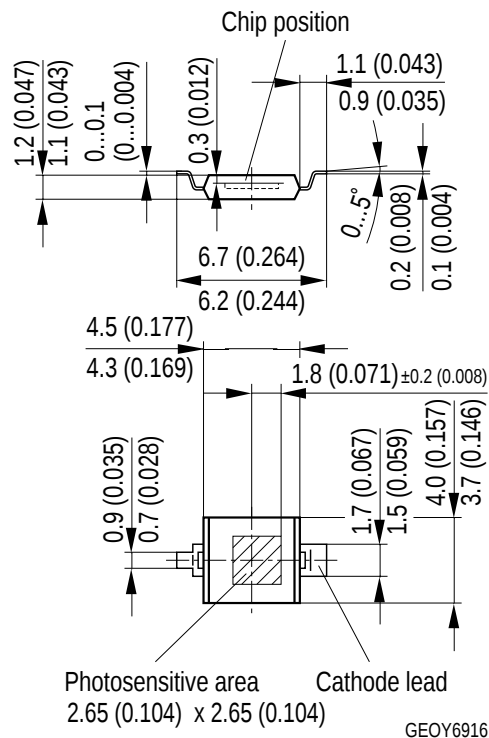
BPW 34 FAS



GEOY6863

Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

BPW 34 FAS (R18R)



Maße werden wie folgt angegeben: mm (inch) / Dimensions are specified as follows: mm (inch).

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Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

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